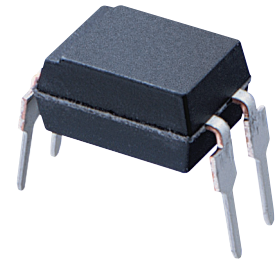


PC817X Series

DIP 4pin General Purpose Photocoupler

*4-channel package type is also available.
(model No. **PC847X Series**)



■ Description

PC817X Series contains an IRED optically coupled to a phototransistor.

It is packaged in a 4pin DIP, available in wide-lead spacing option and SMT gullwing lead-form option.

Input-output isolation voltage(rms) is 5.0kV.

Collector-emitter voltage is 80V(*) and CTR is 50% to 600% at input current of 5mA.

■ Features

1. 4pin DIP package
2. Double transfer mold package (Ideal for Flow Soldering)
3. High collector-emitter voltage (V_{CEO} :80V(*)
4. Current transfer ratio (CTR : MIN. 50% at $I_F=5$ mA, $V_{CE}=5$ V)
5. Several CTR ranks available
6. High isolation voltage between input and output ($V_{iso(rms)}$: 5.0 kV)

(*) Up to Date code "P7" (July 2002) V_{CEO} : 35V.
From the production Date code "J5" (May 1997) to "P7" (July 2002), however the products were screened by $BV_{CEO} \geq 70$ V.

■ Agency approvals/Compliance

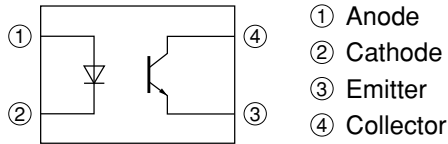
1. Recognized by UL1577 (Double protection isolation), file No. E64380 (as model No. **PC817**)
2. Package resin : UL flammability grade (94V-0)

■ Applications

1. I/O isolation for MCUs (Micro Controller Units)
2. Noise suppression in switching circuits
3. Signal transmission between circuits of different potentials and impedances

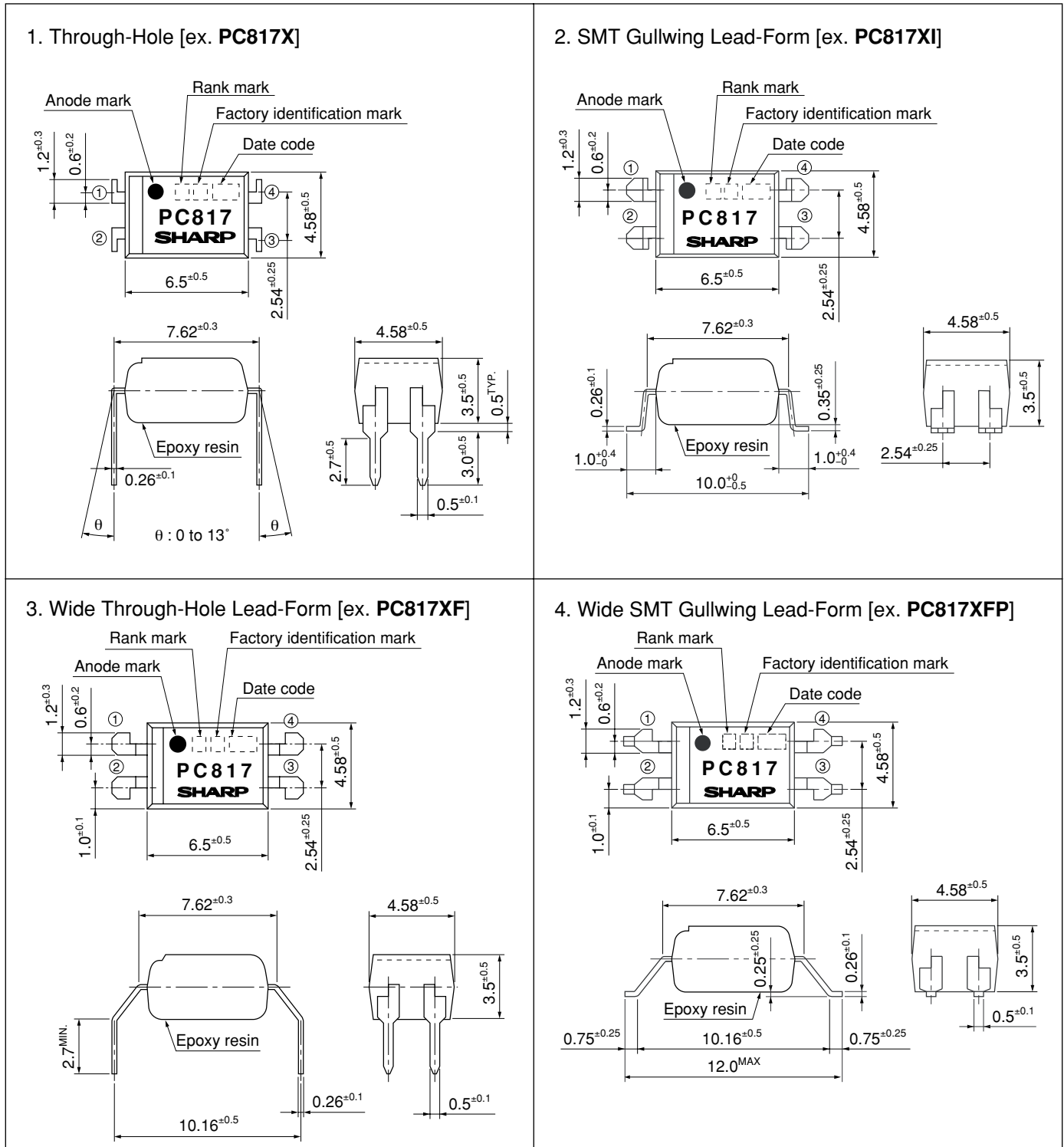
Notice The content of data sheet is subject to change without prior notice.
In the absence of confirmation by device specification sheets, SHARP takes no responsibility for any defects that may occur in equipment using any SHARP devices shown in catalogs, data books, etc. Contact SHARP in order to obtain the latest device specification sheets before using any SHARP device.

Internal Connection Diagram



Outline Dimensions

(Unit : mm)







Product mass : approx. 0.21g

Date code (2 digit)

1st digit				2nd digit	
Year of production				Month of production	
A.D.	Mark	A.D.	Mark	Month	Mark
1990	A	2002	P	January	1
1991	B	2003	R	February	2
1992	C	2004	S	March	3
1993	D	2005	T	April	4
1994	E	2006	U	May	5
1995	F	2007	V	June	6
1996	H	2008	W	July	7
1997	J	2009	X	August	8
1998	K	2010	A	September	9
1999	L	2011	B	October	O
2000	M	2012	C	November	N
2001	N	∴	∴	December	D

repeats in a 20 year cycle

Factory identification mark

Factory identification Mark	Country of origin
no mark	Japan
	
	Indonesia
	Philippines
	China

* This factory marking is for identification purpose only.
Please contact the local SHARP sales representative to see the actual status of the production.

Rank mark

Refer to the Model Line-up table

■ Absolute Maximum Ratings (T_a=25°C)

	Parameter	Symbol	Rating	Unit
Input	Forward current	I _F	50	mA
	*1 Peak forward current	I _{FM}	1	A
	Reverse voltage	V _R	6	V
	Power dissipation	P	70	mW
Output	Collector-emitter voltage	V _{CEO}	*4 80	V
	Emitter-collector voltage	V _{ECO}	6	V
	Collector current	I _C	50	mA
	Collector power dissipation	P _C	150	mW
	Total power dissipation	P _{tot}	200	mW
	*2 Isolation voltage	V _{iso (rms)}	5.0	kV
	Operating temperature	T _{opr}	-30 to +100	°C
	Storage temperature	T _{stg}	-55 to +125	°C
	*3 Soldering temperature	T _{sol}	260	°C

*1 Pulse width ≤ 100μs, Duty ratio : 0.001

*2 40 to 60%RH, AC for 1minute, f=60Hz

*3 For 10s

*4 Up to Date code "P7" (July 2002) V_{CEO} : 35V.

■ Electro-optical Characteristics (T_a=25°C)

	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit	
Input	Forward voltage	V _F	I _F =20mA	-	1.2	1.4	V	
	Peak forward voltage	V _{FM}	I _{FM} =0.5A	-	-	3.0	V	
	Reverse current	I _R	V _R =4V	-	-	10	μA	
	Terminal capacitance	C _t	V=0, f=1kHz	-	30	250	pF	
Output	Collector dark current	I _{CEO}	V _{CE} =50V, I _F =0	-	-	100	nA	
	Collector-emitter breakdown voltage	BV _{CEO}	I _C =0.1mA, I _F =0	*5 80	-	-	V	
	Emitter-collector breakdown voltage	BV _{ECO}	I _E =10μA, I _F =0	6	-	-	V	
Transfer characteristics	Collector current	I _C	I _F =5mA, V _{CE} =5V	2.5	-	30.0	mA	
	Collector-emitter saturation voltage	V _{CE (sat)}	I _F =20mA, I _C =1mA	-	0.1	0.2	V	
	Isolation resistance	R _{ISO}	DC500V, 40 to 60%RH	5×10 ¹⁰	1×10 ¹¹	-	Ω	
	Floating capacitance	C _f	V=0, f=1MHz	-	0.6	1.0	pF	
	Cut-off frequency	f _c	V _{CE} =5V, I _C =2mA, R _L =100Ω, -3dB	-	80	-	kHz	
	Response time	Rise time	t _r	V _{CE} =2V, I _C =2mA, R _L =100Ω	-	4	18	μs
		Fall time	t _f		-	3	18	μs

*5 From the production Date code "J5" (May 1997) to "P7" (July 2002), however the products were screened by BV_{CEO}≥70V.

■ Model Line-up

Lead Form	Through-Hole	Wide Through-Hole	SMT Gullwing		Wide SMT Gullwing	Rank mark	I _C [mA] (I _F =5mA, V _{CE} =5V, T _a =25°C)
Package	Sleeve 100pcs/sleeve		Taping 2 000pcs/reel				
Model No.	PC817X	PC817XF	PC817XI	PC817XP	PC817XFP	with or without	2.5 to 30.0
	PC817X1	PC817XF1	PC817XI1	PC817XP1	–	A	4.0 to 8.0
	PC817X2	PC817XF2	PC817XI2	PC817XP2	–	B	6.5 to 13.0
	PC817X3	PC817XF3	PC817XI3	PC817XP3	–	C	10.0 to 20.0
	PC817X4	PC817XF4	PC817XI4	PC817XP4	–	D	15.0 to 30.0
	PC817X5	PC817XF5	PC817XI5	PC817XP5	–	A or B	4.0 to 13.0
	PC817X6	PC817XF6	PC817XI6	PC817XP6	–	B or C	6.5 to 20.0
	PC817X7	PC817XF7	PC817XI7	PC817XP7	–	C or D	10.0 to 30.0
	PC817X8	PC817XF8	PC817XI8	PC817XP8	–	A, B or C	4.0 to 20.0
	PC817X9	PC817XF9	PC817XI9	PC817XP9	–	B, C or D	6.5 to 30.0
	PC817X0	PC817XF0	PC817XI0	PC817XP0	–	A, B, C or D	4.0 to 30.0

Please contact a local SHARP sales representative to inquire about production status and Lead-Free options.

Fig.1 Forward Current vs. Ambient Temperature

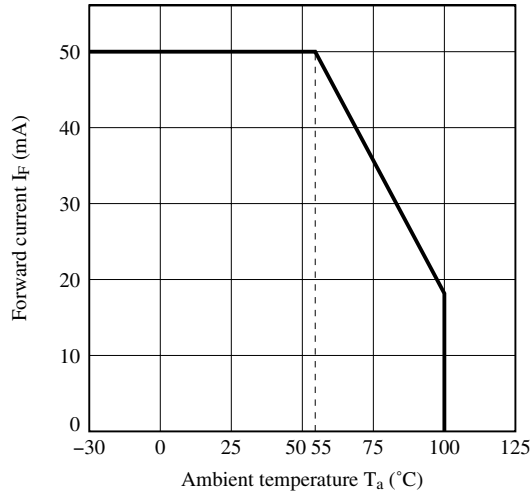


Fig.2 Diode Power Dissipation vs. Ambient Temperature

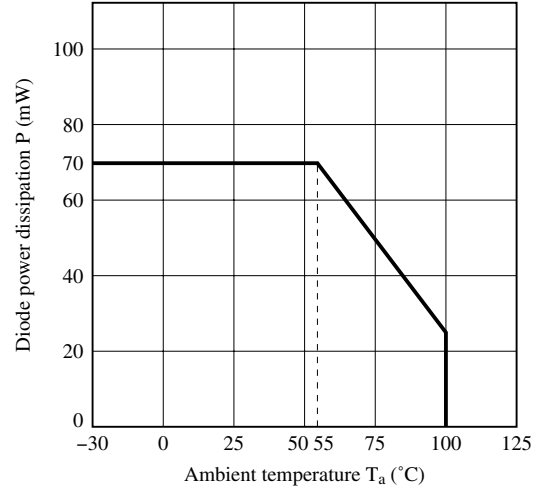


Fig.3 Collector Power Dissipation vs. Ambient Temperature

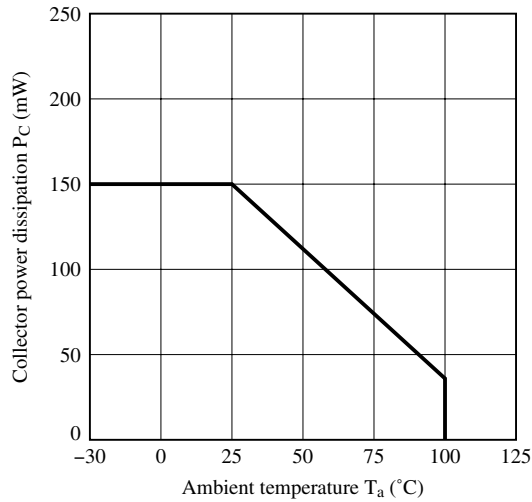


Fig.4 Total Power Dissipation vs. Ambient Temperature

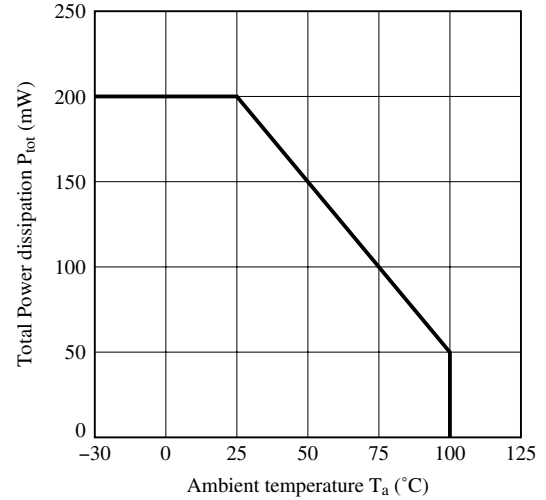


Fig.5 Peak Forward Current vs. Duty Ratio

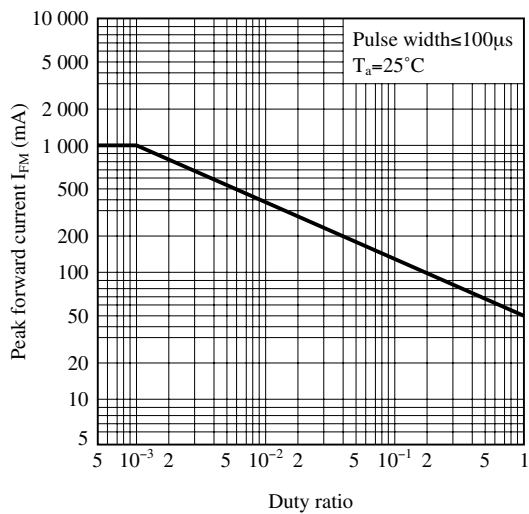


Fig.6 Current Transfer Ratio vs. Forward Current

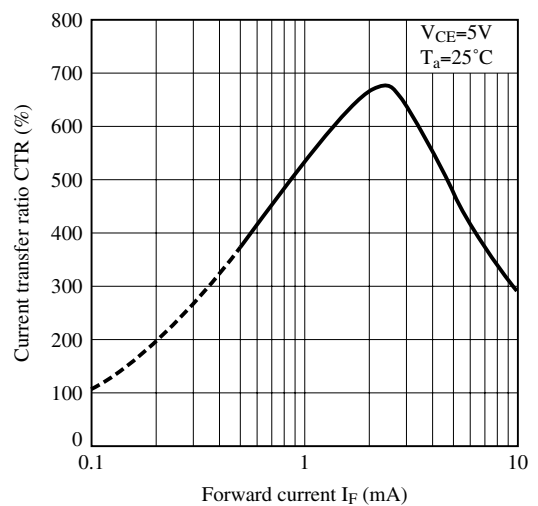


Fig.7 Forward Current vs. Forward Voltage

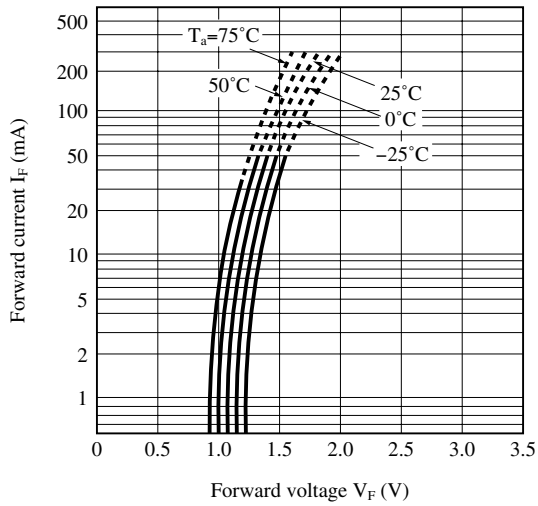


Fig.8 Collector Current vs. Collector-emitter Voltage

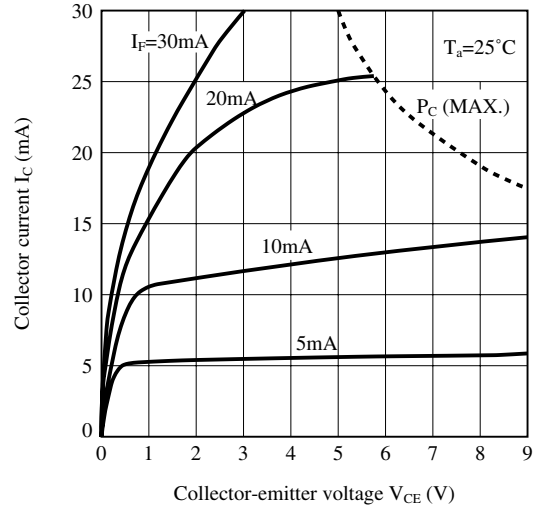


Fig.9 Relative Current Transfer Ratio vs. Ambient Temperature

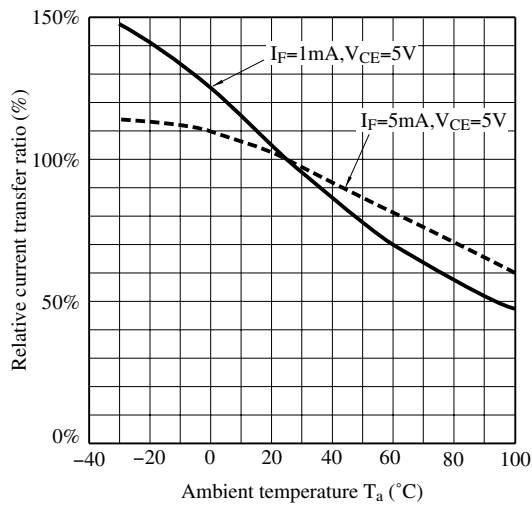


Fig.10 Collector - emitter Saturation Voltage vs. Ambient Temperature

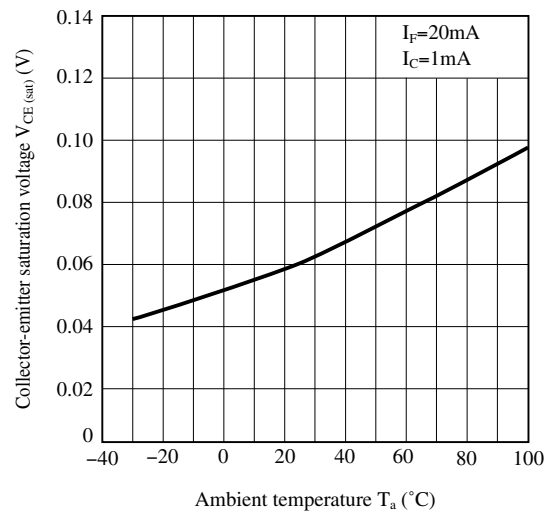


Fig.11 Collector Dark Current vs. Ambient Temperature

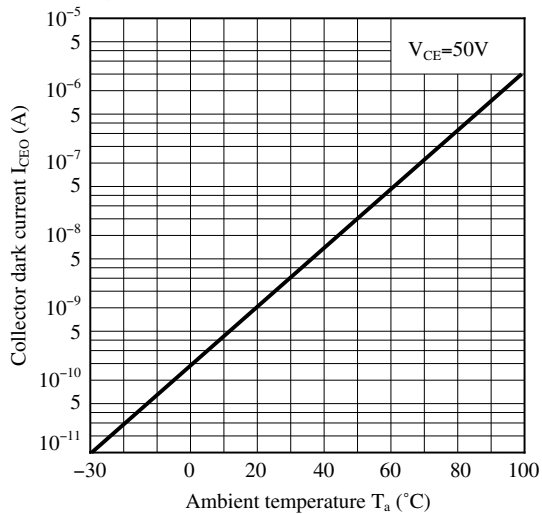


Fig.12 Collector-emitter Saturation Voltage vs. Forward Current

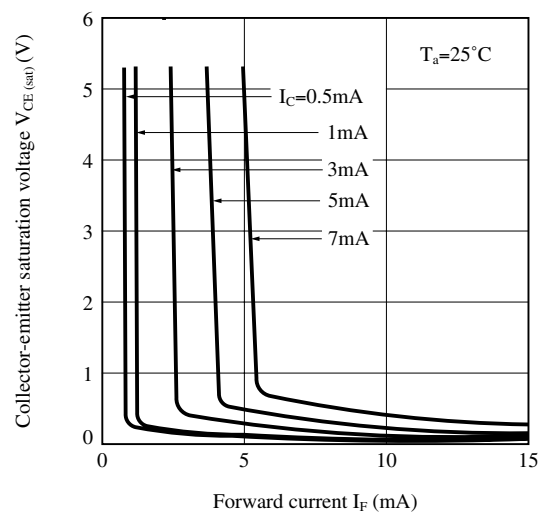


Fig.13 Response Time vs. Load Resistance

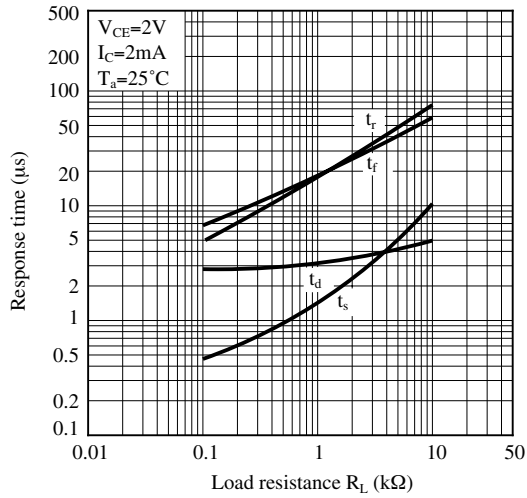
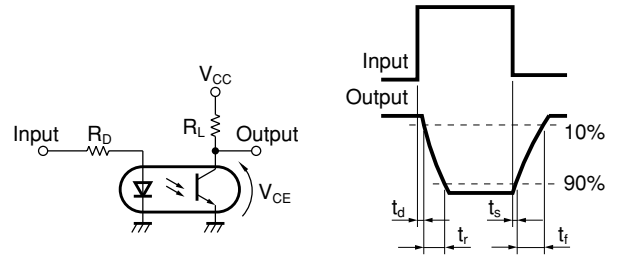


Fig.14 Test Circuit for Response Time



Please refer to the conditions in Fig.13.

Fig.15 Frequency Response

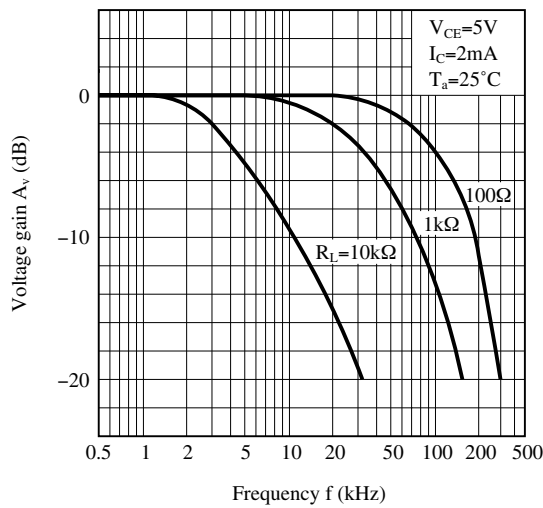
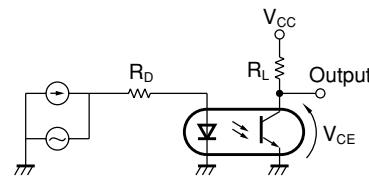


Fig.16 Test Circuit for Frequency Response



Please refer to the conditions in Fig.15.

Remarks : Please be aware that all data in the graph are just for reference and not for guarantee.

■ **Design Considerations**

● **Design guide**

While operating at $I_F < 1.0\text{mA}$, CTR variation may increase.
Please make design considering this fact.

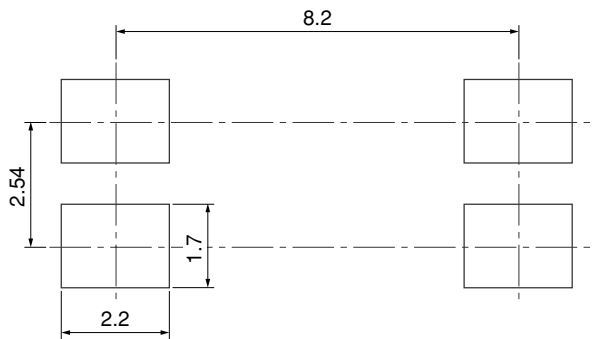
This product is not designed against irradiation and incorporates non-coherent IRED.

● **Degradation**

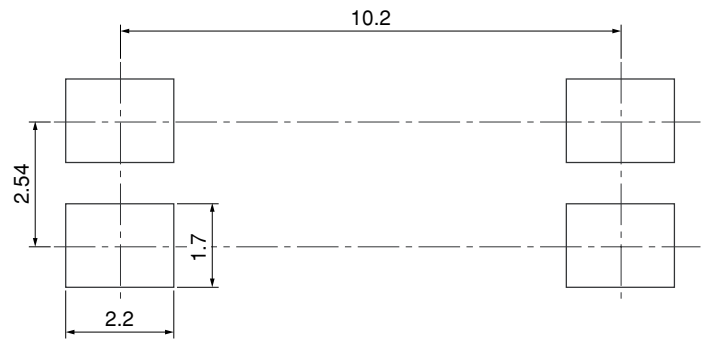
In general, the emission of the IRED used in photocouplers will degrade over time.
In the case of long term operation, please take the general IRED degradation (50% degradation over 5years) into the design consideration.

● **Recommended Foot Print (reference)**

SMT Gullwing Lead-form



Wide SMT Gullwing Lead-form



(Unit : mm)

☆ For additional design assistance, please review our corresponding Optoelectronic Application Notes.

■ Manufacturing Guidelines

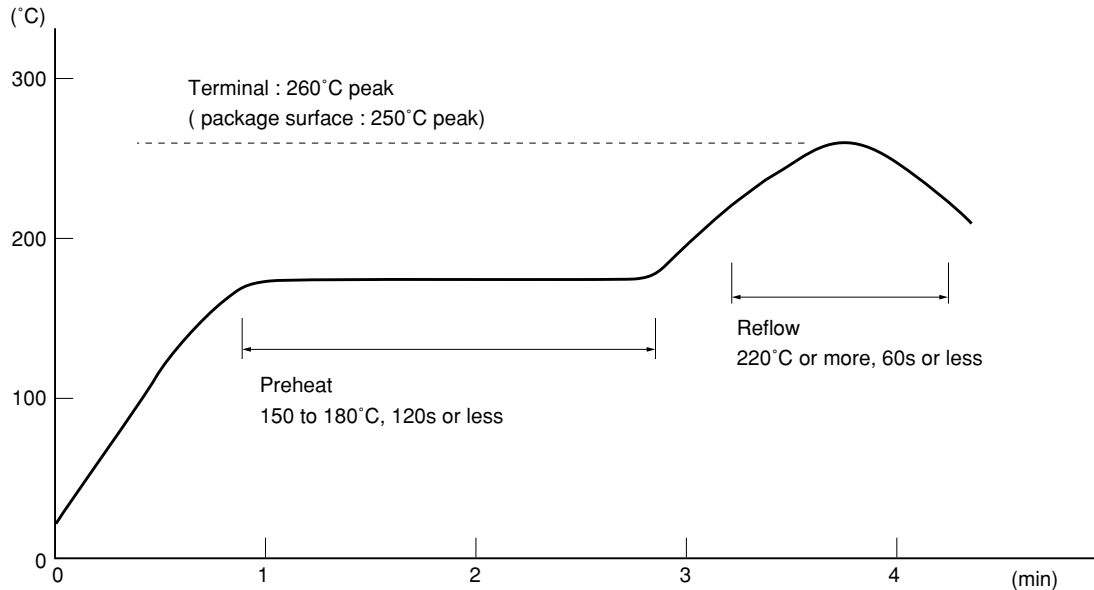
● Soldering Method

Reflow Soldering:

Reflow soldering should follow the temperature profile shown below.

Soldering should not exceed the curve of temperature profile and time.

Please don't solder more than twice.



Flow Soldering :

Due to SHARP's double transfer mold construction submersion in flow solder bath is allowed under the below listed guidelines.

Flow soldering should be completed below 270°C and within 10s.

Preheating is within the bounds of 100 to 150°C and 30 to 80s.

Please don't solder more than twice.

Hand soldering

Hand soldering should be completed within 3s when the point of solder iron is below 400°C.

Please don't solder more than twice.

Other notices

Please test the soldering method in actual condition and make sure the soldering works fine, since the impact on the junction between the device and PCB varies depending on the tooling and soldering conditions.

● Cleaning instructions**Solvent cleaning:**

Solvent temperature should be 45°C or below Immersion time should be 3minutes or less

Ultrasonic cleaning:

The impact on the device varies depending on the size of the cleaning bath, ultrasonic output, cleaning time, size of PCB and mounting method of the device.

Therefore, please make sure the device withstands the ultrasonic cleaning in actual conditions in advance of mass production.

Recommended solvent materials:

Ethyl alcohol, Methyl alcohol and Isopropyl alcohol

In case the other type of solvent materials are intended to be used, please make sure they work fine in actual using conditions since some materials may erode the packaging resin.

● Presence of ODC

This product shall not contain the following materials.

And they are not used in the production process for this device.

Regulation substances:CFCs, Halon, Carbon tetrachloride, 1.1.1-Trichloroethane (Methylchloroform)

Specific brominated flame retardants such as the PBBOs and PBBs are not used in this product at all.

■ **Package specification**

● **Sleeve package**

1. Through-Hole or SMT Gullwing Lead-Form

Package materials

Sleeve : HIPS (with anti-static material)

Stopper : Styrene-Elastomer

Package method

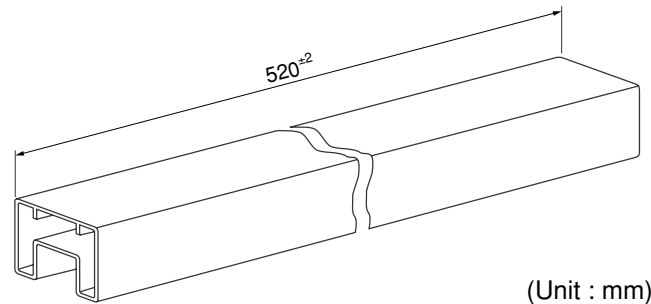
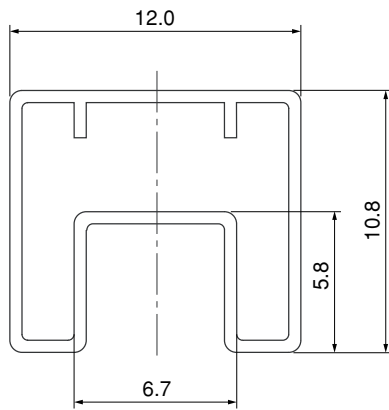
MAX. 100pcs of products shall be packaged in a sleeve.

Both ends shall be closed by tabbed and tabless stoppers.

The product shall be arranged in the sleeve with its anode mark on the tabless stopper side.

MAX. 20 sleeves in one case.

Sleeve outline dimensions



2. Wide Through-Hole Lead-Form or Wide SMT Gullwing Lead-Form

Package materials

Sleeve : HIPS (with anti-static material)

Stopper : Styrene-Elastomer

Package method

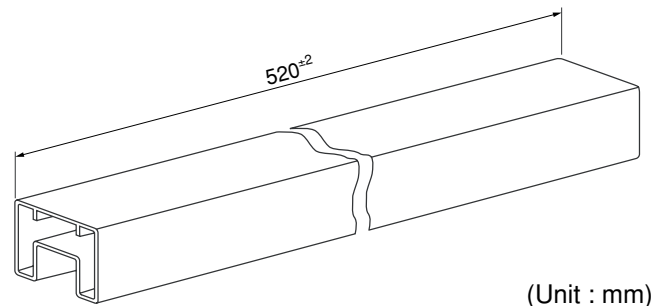
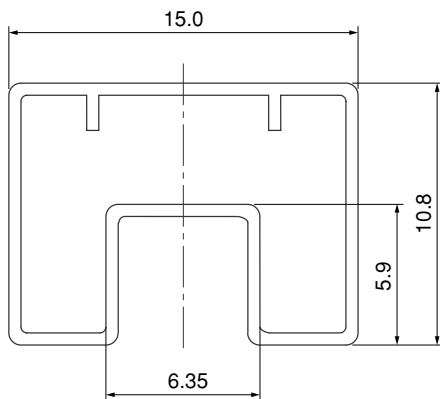
MAX. 100pcs of products shall be packaged in a sleeve.

Both ends shall be closed by tabbed and tabless stoppers.

The product shall be arranged in the sleeve with its anode mark on the tabless stopper side.

MAX. 20 sleeves in one case.

Sleeve outline dimensions



● **Tape and Reel package**

1. SMT Gullwing

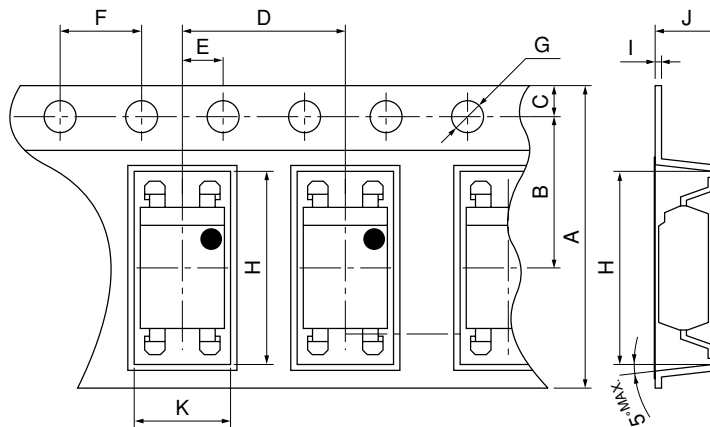
Package materials

Carrier tape : PS

Cover tape : PET (three layer system)

Reel : PS

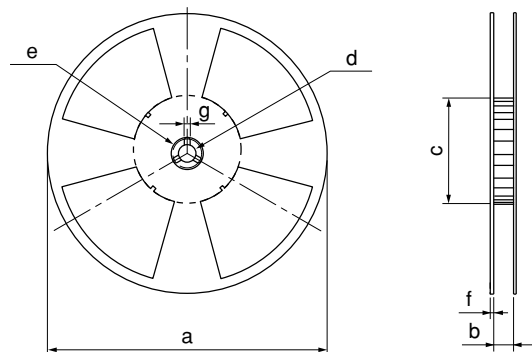
Carrier tape structure and Dimensions



Dimensions List (Unit : mm)

A	B	C	D	E	F	G
16.0 \pm 0.3	7.5 \pm 0.1	1.75 \pm 0.1	8.0 \pm 0.1	2.0 \pm 0.1	4.0 \pm 0.1	ϕ 1.5 \pm 0.1
H	I	J	K			
10.4 \pm 0.1	0.4 \pm 0.05	4.2 \pm 0.1	5.1 \pm 0.1			

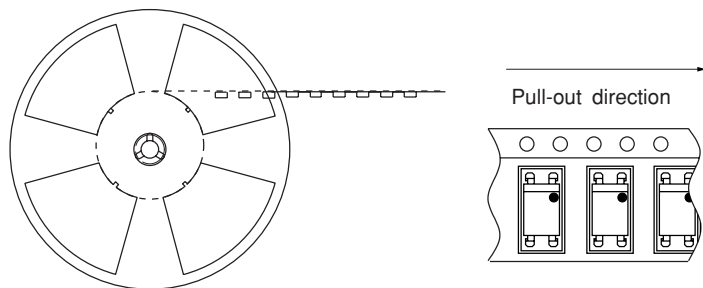
Reel structure and Dimensions



Dimensions List (Unit : mm)

a	b	c	d
330	17.5 \pm 1.5	100 \pm 1.0	13 \pm 0.5
e	f	g	
23 \pm 1.0	2.0 \pm 0.5	2.0 \pm 0.5	

Direction of product insertion



[Packing : 2 000pcs/reel]

2. Wide SMT Gullwing

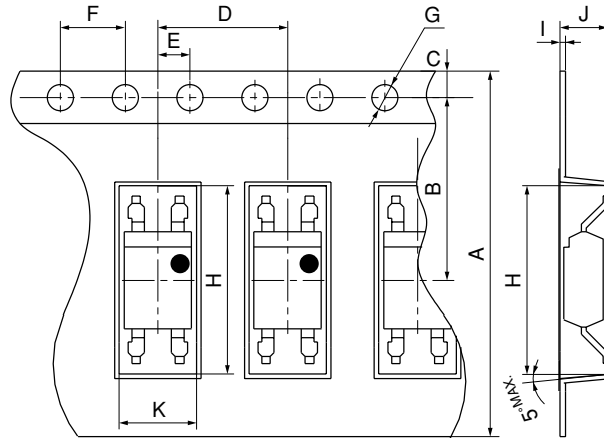
Package materials

Carrier tape : PS

Cover tape : PET (three layer system)

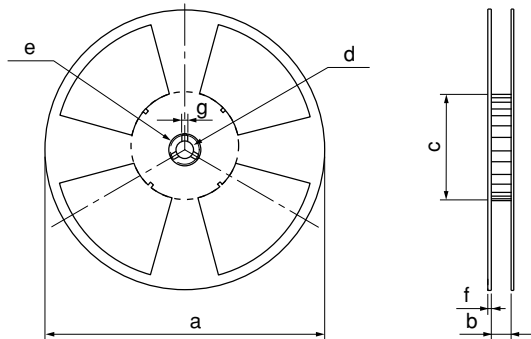
Reel : PS

Carrier tape structure and Dimensions



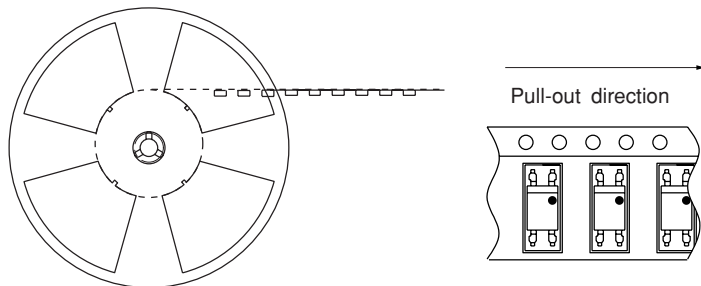
Dimensions List (Unit : mm)						
A	B	C	D	E	F	G
24.0 \pm 0.3	11.5 \pm 0.1	1.75 \pm 0.1	8.0 \pm 0.1	2.0 \pm 0.1	4.0 \pm 0.1	ϕ 1.5 \pm 0.1
H	I	J	K			
12.4 \pm 0.1	0.4 \pm 0.05	4.1 \pm 0.1	5.1 \pm 0.1			

Reel structure and Dimensions



Dimensions List (Unit : mm)			
a	b	c	d
330	25.5 \pm 1.5	100 \pm 1.0	13 \pm 0.5
e	f	g	
23 \pm 1.0	2.0 \pm 0.5	2.0 \pm 0.5	

Direction of product insertion



[Packing : 2 000pcs/reel]

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(i) The devices in this publication are designed for use in general electronic equipment designs such as:

- Personal computers
- Office automation equipment
- Telecommunication equipment [terminal]
- Test and measurement equipment
- Industrial control
- Audio visual equipment
- Consumer electronics

(ii) Measures such as fail-safe function and redundant design should be taken to ensure reliability and safety when SHARP devices are used for or in connection

with equipment that requires higher reliability such as:

- Transportation control and safety equipment (i.e., aircraft, trains, automobiles, etc.)
- Traffic signals
- Gas leakage sensor breakers
- Alarm equipment
- Various safety devices, etc.

(iii) SHARP devices shall not be used for or in connection with equipment that requires an extremely high level of reliability and safety such as:

- Space applications
- Telecommunication equipment [trunk lines]
- Nuclear power control equipment
- Medical and other life support equipment (e.g., scuba).

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